

Crystalline Thin Films: The Electrochemical Atomic Layer Deposition (ECALD) view

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Outline

- Acknowledgements
- Context: Crystalline Thin films
- What is ECALD?
 - Mechanism
- Instrumental set-up
- Applications
 - Electrocatalysis
 - Deposition on various substrates: work done @ EaP
 - Compound semiconductor
- Conclusions

Acknowledgements

- Dr. Tumaini Mkwizu, PhD work on ECALD
- Ms. Nikiwe Kunjuzwa, PhD student- ECALD and batteries
- Prof. Kenneth Ozoemena, Research group leader and electrochemist
- Dr Mkhulu Mathe, Competence area manager, electrochemist and ECALD expert

Crystalline Thin Films

- Application

- Historical: light absorber material
CdTe, crystalline Si
- Modern: light absorber material – Solar cells
Cu, In, Ga, Se (CIGS)- developed by Vivian Alberts and UJ
- low material cost in 2011- potentially low fabrication costs

- Growth methodologies

- Molecular beam epitaxy/ chemical vapour deposition
Disadvantages: expensive equipment, use toxic precursors,
Vacuum and High Temperature
- Electrochemical methods: co-deposition, precipitation
Disadvantages: lack of control during deposition

What is ECALD?

- Definition:

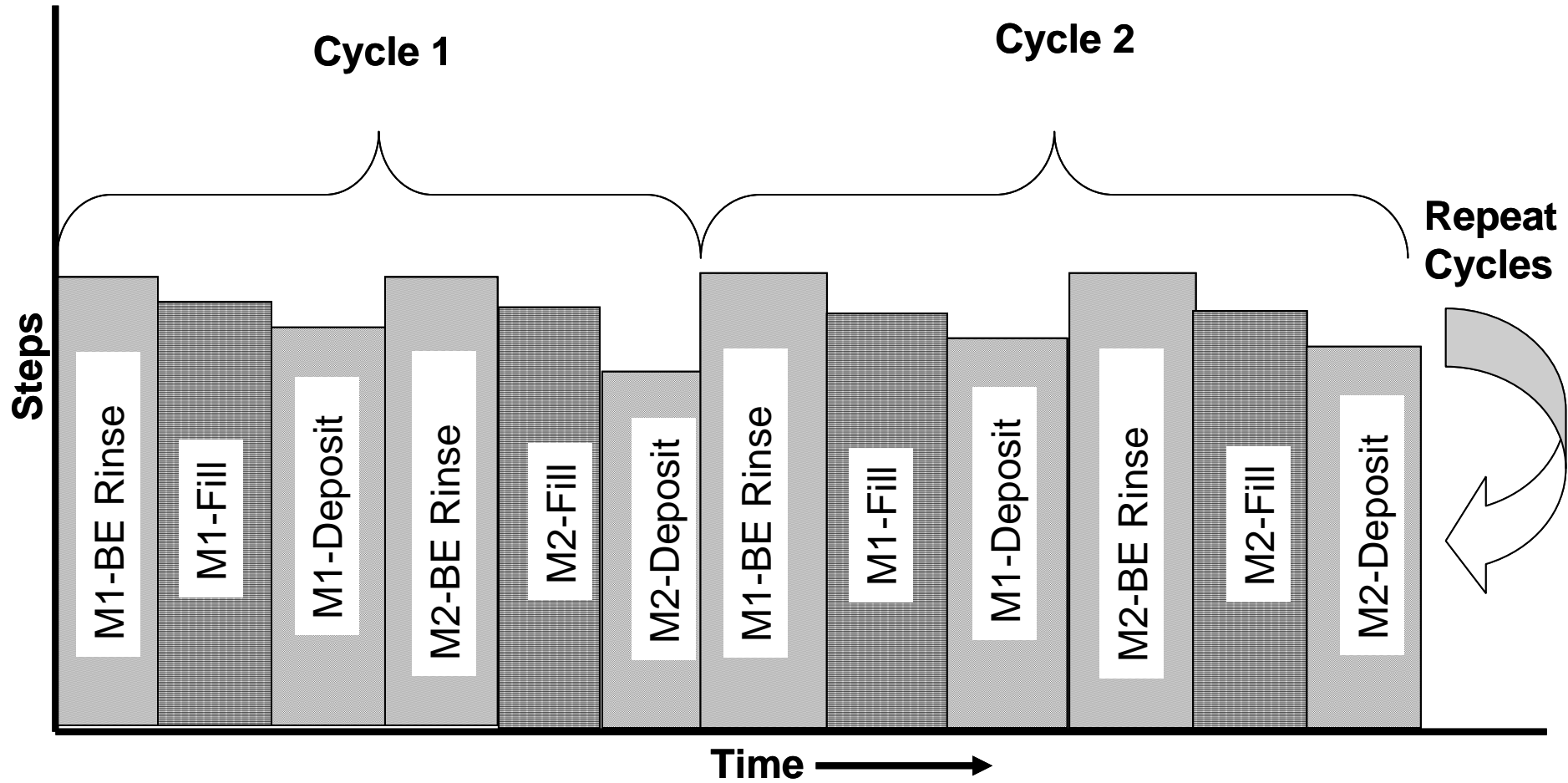
alternated electrodeposition of atomic layers of elements on a substrate, employing under-potential deposition (UPD) in which one element deposits onto another element at a voltage prior to that necessary to deposit the element onto itself.

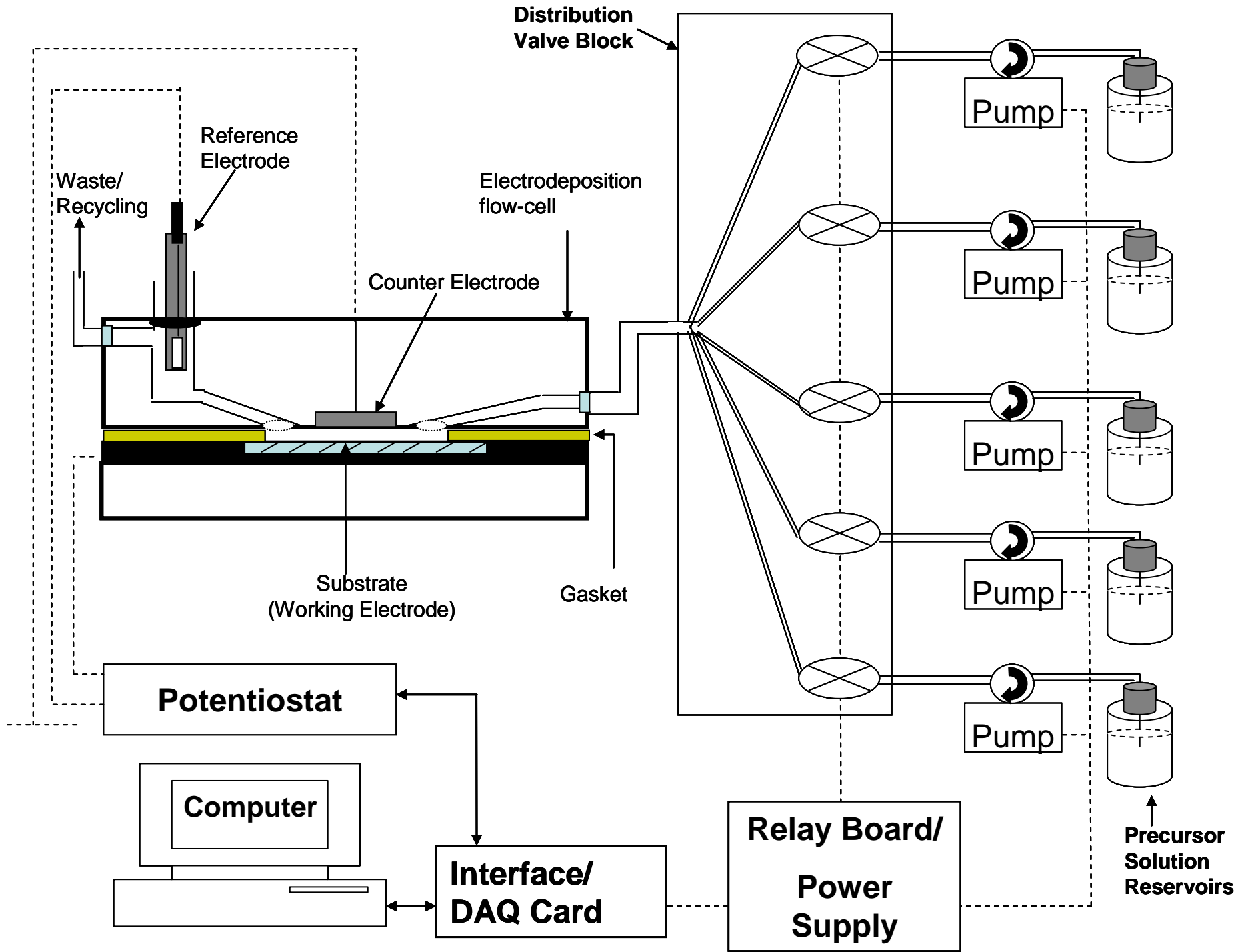
- Advantages:

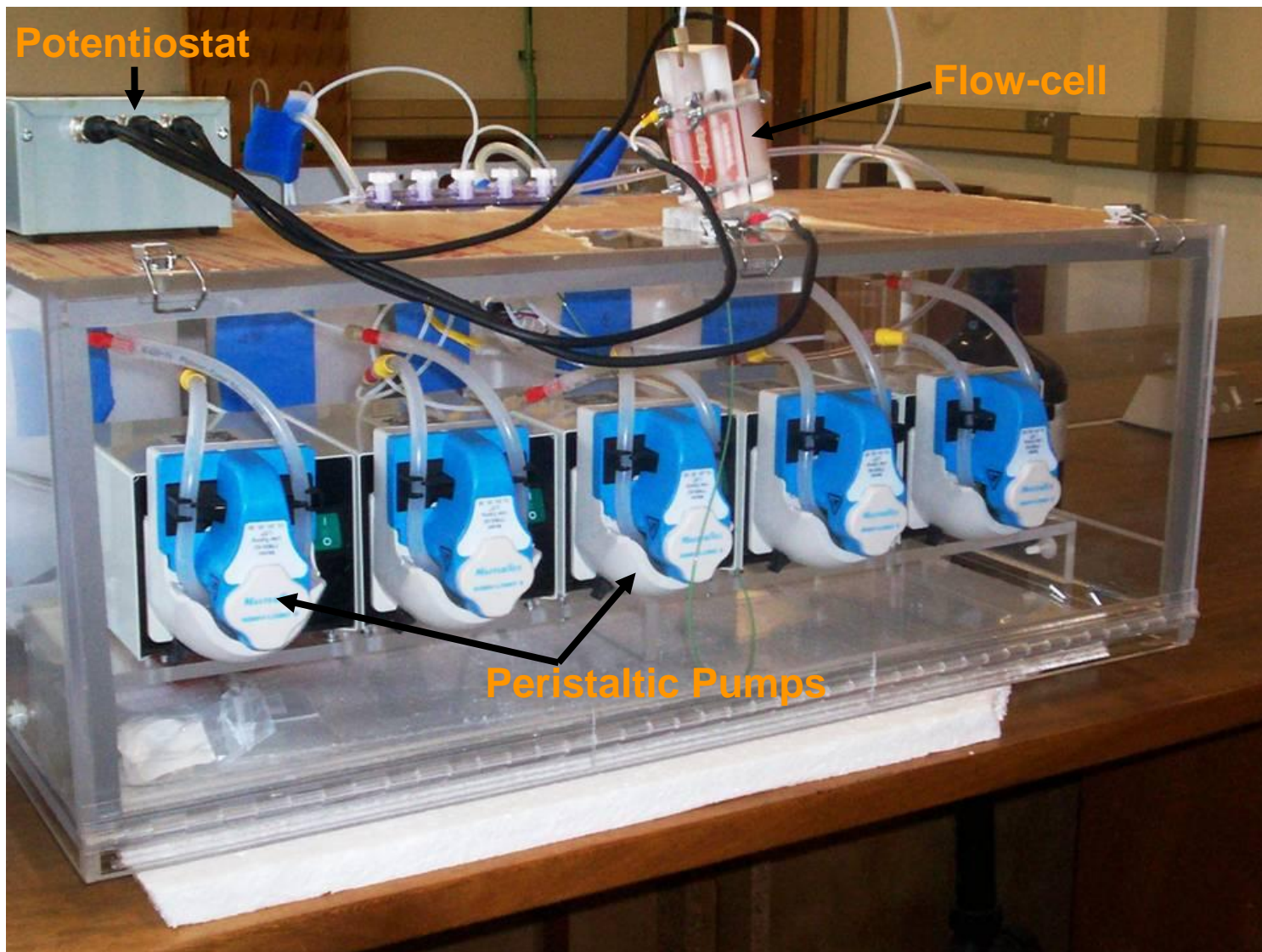
- ambient temperature,
- use small concentrations of precursor solutions,
- optimized solutions and potential separately

Offers **atomic layer control**- fundamental for controlled growth processes

Mechanism-Sequential deposition







**Instrumental set-up – Pumping system,
Potentiostat and Flow-Cell Connectivity**

APPLICATIONS

- Electrocatalysis

Noble-Metals studied = Pt, Ru, Au, Pd

Substrates = Carbon materials-fuel cell carbon paper,
Gold films

T.S.Mkwizu, M.K. Mathe, and I. Cukrowski, ECS Transactions, Vol.19, 97-113 (2009)

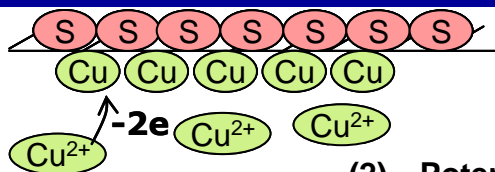
T.S.Mkwizu, M.K. Mathe, and I. Cukrowski, Langmuir, Vol. 26, 570 - 580 (2010)

T.S Mkwizu, M.R. Modibedi, and M. K. Mathe, 219th ECS Meeting (2011)

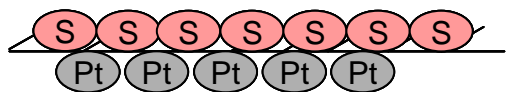
Sequential electrodeposition coupled to Surface-limited Redox-replacement reactions: Synthesis of multilayered bimetallic RuPt electrocatalyst



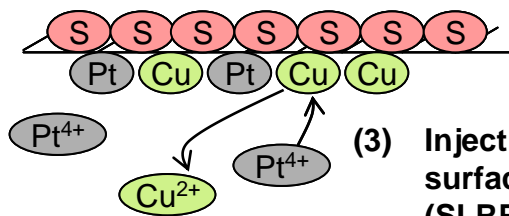
(1) Clean substrate with blank electrolyte (BE);
Inject Cu^{2+} solution at $E \gg E_{\text{Cu-Cu}^{2+}}$



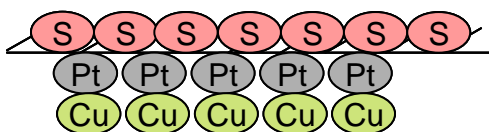
(2) Potentiostatic electrodeposition at $-E_{\text{dep}} > E_{\text{Cu-Cu}^{2+}}$ (Underpotential Deposition (UPD)) or $-E_{\text{dep}} < E_{\text{Cu-Cu}^{2+}}$ (small Overpotential Deposition (OPD)) - to produce sacrificial Cu adlayer on active sites of the substrate; Rinse with BE



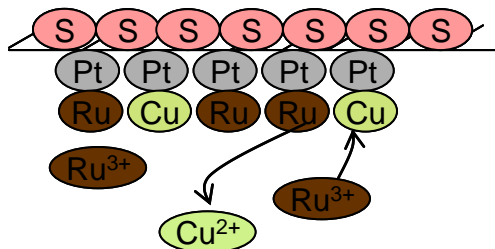
(4) Pt nanodeposit on substrate;
Rinse with BE and inject Cu^{2+} solution at $E \gg E_{\text{Cu-Cu}^{2+}}$



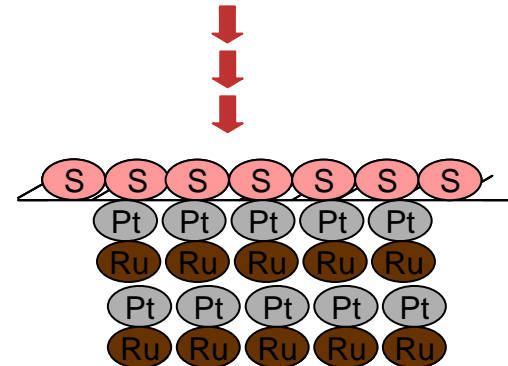
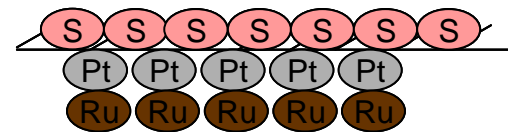
(3) Inject H_2PtCl_6 solution and allow surface-limited redox-replacement (SLRR) of Cu by Pt at open circuit (OC)



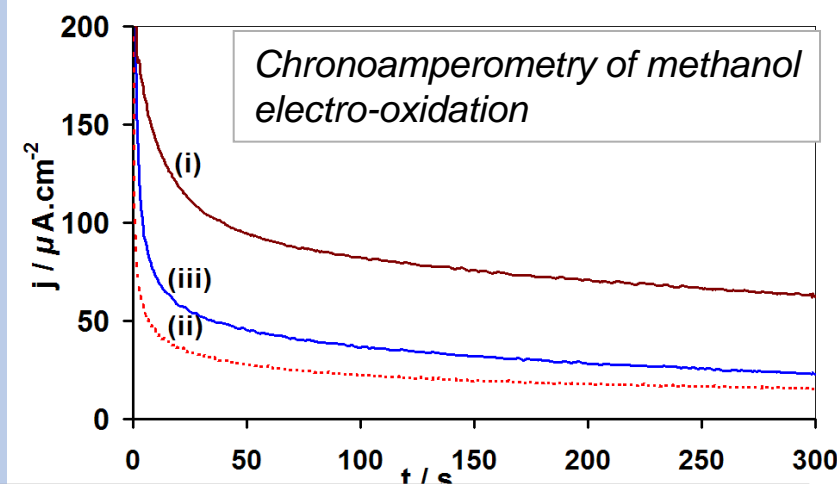
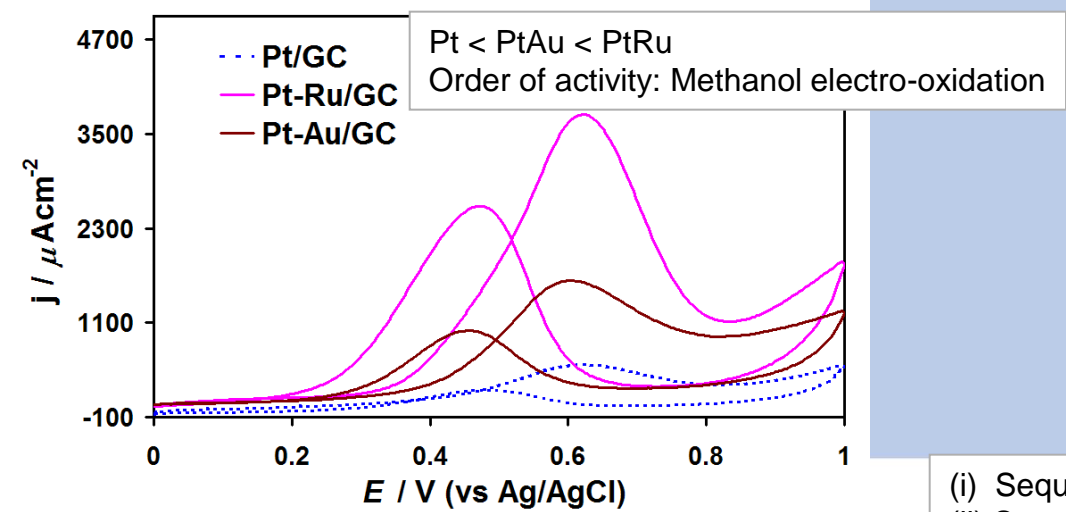
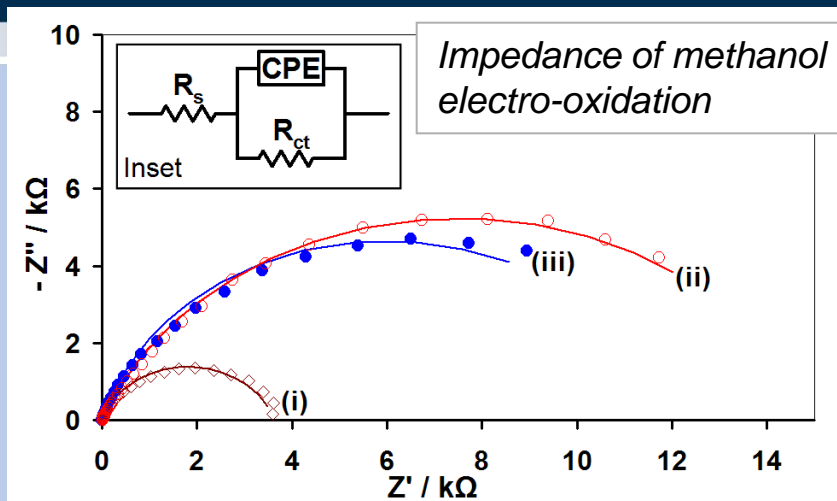
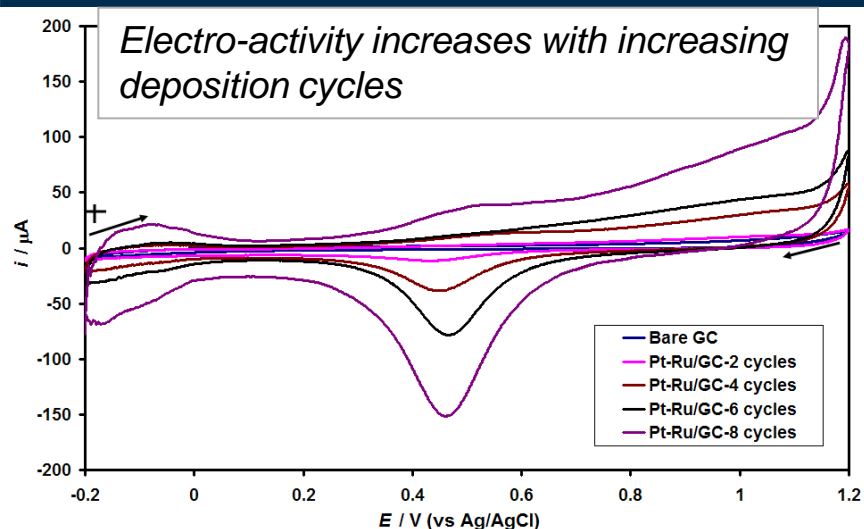
(5) Potentiostatic electrodeposition at $-E_{\text{dep}}$ to produce sacrificial Cu adlayer on active sites on Pt adlayers; Rinse with BE



(6) Inject RuCl_3 solution and allow surface-limited redox-replacement (SLRR) of Cu by Ru at OC

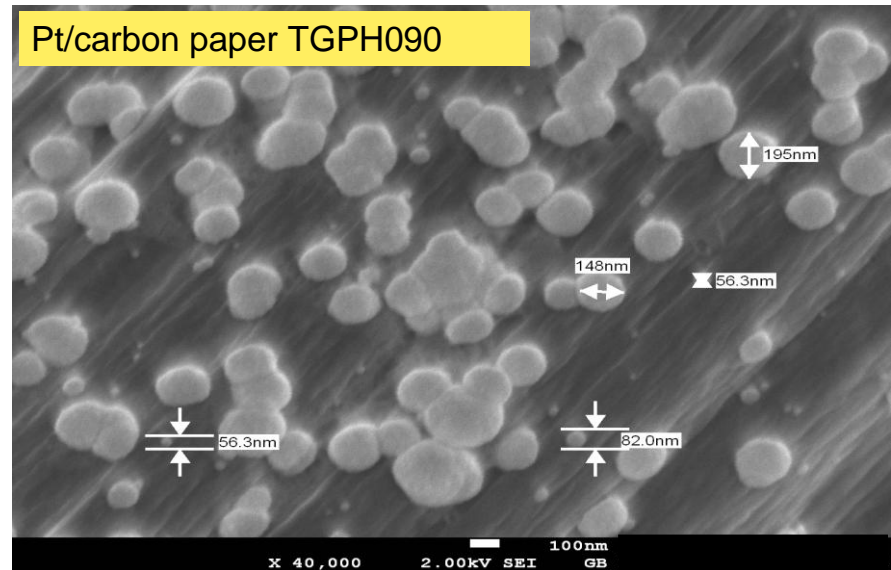
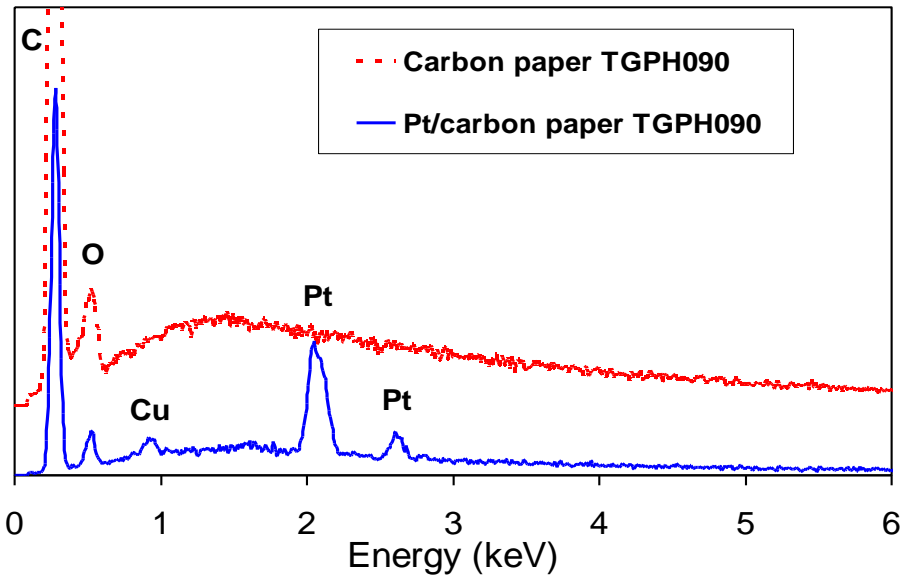
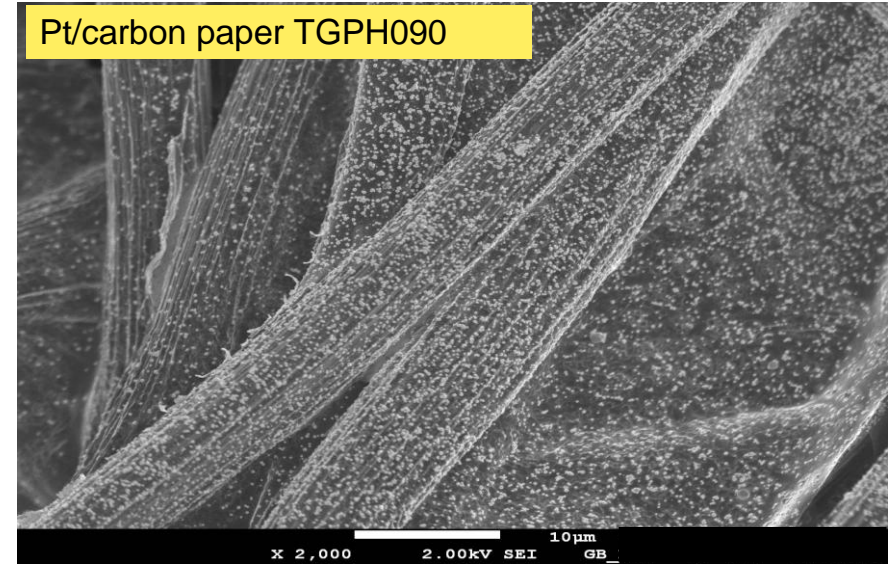
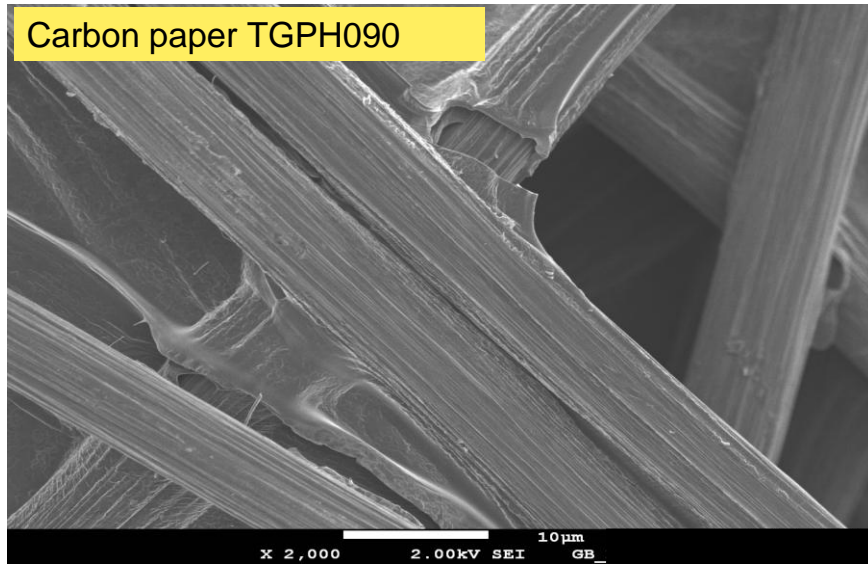


Tuning Electrocatalysis: Electrochemical Characterisation

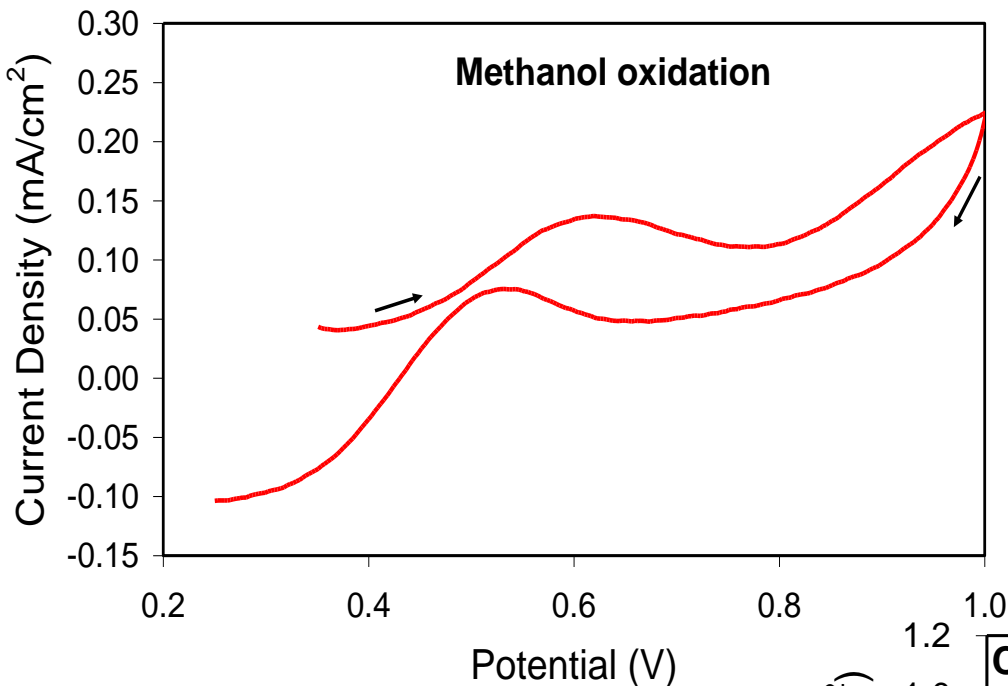


- (i) Sequentially-deposited with Cu SLRR bimetallic PtRu / GC
- (ii) Sequentially- *codeposited* with Cu SLRR bimetallic Pt-Ru/GC
- (iii) Sequentially-deposited with Cu SLRR monometallic Pt/GC

Tuning Electrocatalysis on Fuel Cell gas diffusion layer: SEM micrographs and EDX profile

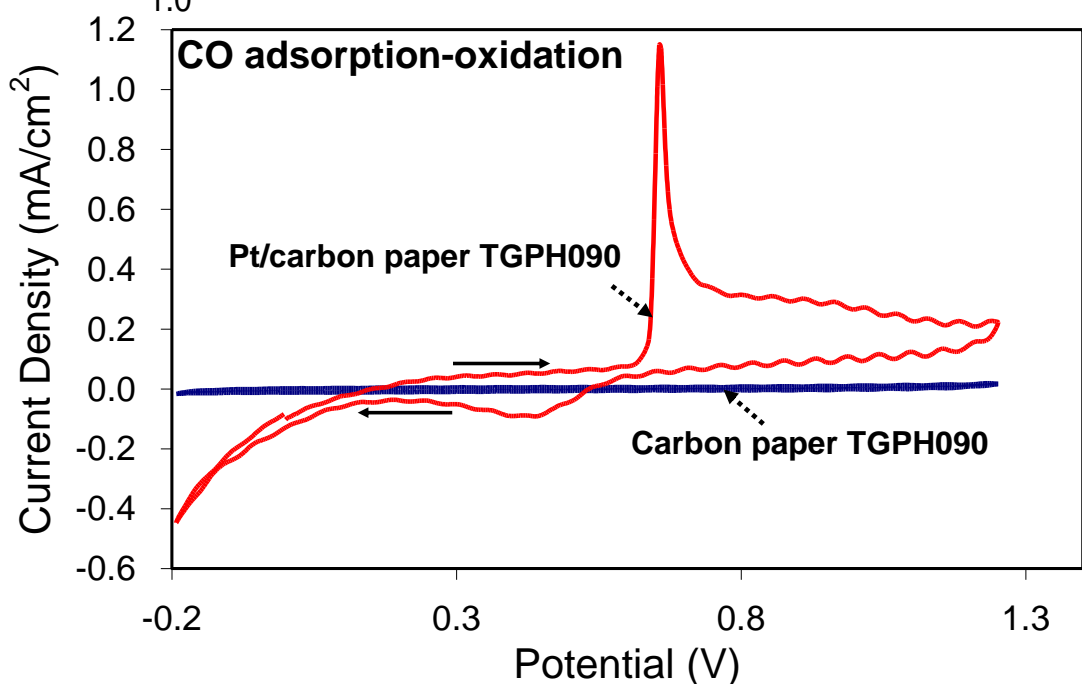


Tuning Electrocatalysis on Fuel Cell gas diffusion layer: Electrochemical Characterisation



Cyclic voltammograms at 50 mV/s in
(i) 0.1 M HClO₄ + 0.1 M Methanol

(ii) 0.1 M HClO₄ + CO



• Compound Semiconductors

- **Group II - VI, Group III - V , Group IV - VI: Optoelectronic materials**

CdTe, CdSe, GaAs, HgSe - photovoltaics, photon sensors, lasers etc.

- **Substrates = Gold, carbon material**

Mkhulu K. Mathe et al. J. Electrochem. Soc., Volume 152, Issue 11, C751-C755 (2005)

Mkhulu K. Mathe et al. J. Crystal Growth Volume 271, Issues 1-2, 55-64 (2004)

• Energy storage

- **Physical form (capacitors) and Electrochemical form (batteries)**
- **Obstacle to increasing thin film battery storage capacity:** limited diffusion path length of ions and electrons
- **Solution: area enhancement- 3D thin films**
 - Increases total amount of active material while maintaining short diffusion path
 - Results- high power and energy density

Conclusions

- ECALD:
 - controlled growth of thin film deposits
 - atomic layer control is key to reducing the amount of PEMFC catalysts
 - possibility of a 3D battery stack

Thank You

